O.brixx A106



Measurement Module for Strain Gage and LVDT/RVDT

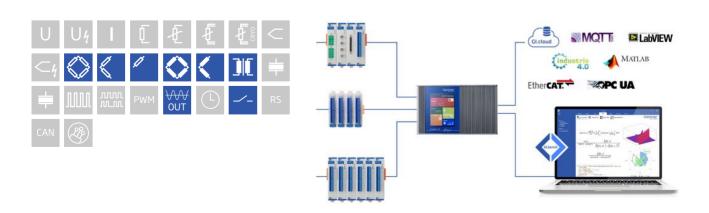
Q.brixx brings the performance and functionality of Q.bloxx into a scalable, portable, and rugged form factor. Q.brixx DAQ systems can consist of up to 16 measurement modules and an integrated, high-performance controller for communication, control, and data logging purposes. With a robust aluminum housing capable of withstanding severe shock and vibration, Q.brixx is ideal for on-the-go applications in potentially harsh environments.

- Ectromagnetic compatibility according EN 61000-4 and EN 55011
- Robust and reliable stable and compact aluminum housing, easy to carry
- Power supply 10 ... 30 VDC
- Temperature range -20 up to +60°C
- High density and flexibility up to 16 modules in one system in any constellation



Key Features

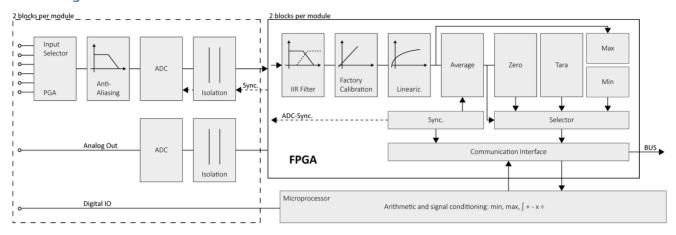
- 2 galvanically isolated analog inputs channels strain gage and inductive half and full bridges, LVDT, RVDT quarter bridge with completion terminal
- DC and carrier frequency (CF) principle 2.5 and 5 VDC excitation, 2.5 and 5 VDCeff excitation carrier frequency, 600 Hz or 4.8 kHz configurable per channel
- 2 Analog output channels ±10 VDC, 10 kHz update rate per channel
- High-accuracy digitization 24-bit ADC, 10 kHz sample rate per channel
- 4 digital I/Os input: state, tare, memory reset, output: state, alarm, threshold
- Signal conditioning linearization, filtering, average, scaling, min/max, RMS, arithmetic, alarm
- 3-Way galvanic isolation 500 VDC channel to channel, channel to power supply, and channel to bus





Measurement Module for Strain Gage and LVDT/RVDT

Block diagram



Technical Data

Analog Input

| Channels | 2 |
|-------------------|--|
| Accuracy | 0.02 % typical |
| | 0.05 % in controlled environment ¹ |
| | 0.1 % in industrial area ² |
| Linearity error | 0.02 % typical full-scale |
| Repeatability | 0.01 % typical (within 24 hrs) |
| Input impedance | >10 MΩ |
| Isolation voltage | 500 VDC channel to channel, to power supply, channel to bus ³ |

 $^{^{\}rm 1}$ according to EN 61326 2006: appendix B

Analog to Digital Conversion

| Resolution | 24-bit |
|----------------------|---|
| Sample rate | 10 kHz per channel |
| Modulation method | sigma-delta |
| Anti-aliasing filter | 2 kHz, 3rd order (DC excitation) 1 kHz, 3rd order (4.8 kHz CF excitation) 100 Hz, 3rd order (600 Hz CF excitation) |
| Digital filters | Infinite impulse response (IIR), low-pass, high-pass, band-pass, band-stop, to 8th order Butterworth or Bessel, frequency range 0.1 Hz to 1 kHz in steps of 0.1 (adjustable via software) |
| Averaging | configurable or automatic according to the user-defined data rate |

² according to EN 61326 2006: appendix A

 $^{^{\}rm 3}$ noise pulses up to 1000 VDC, continuous up to 250 VDC



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Analog Output

| Channels | 2 | |
|---------------------------|--------------------------|----------------------------|
| Accuracy | 0.02 % typical | |
| Voltage output | ±10 VDC | |
| Allowable load resistance | >2 kΩ | |
| Long-term drift | <1 mV / 24 hrs | <2.5 mV / 8000 hrs |
| Temperature drift | <1 mV /10 K Offset drift | < 0.05 % / 10 K Gain drift |
| Noise voltage | <2 mV at 10 Hz | <10 mV at 1 kHz |

Digital Input & Output

| Channels | 4 configurable I/Os |
|----------------------|---|
| Mode(s) of operation | status |
| Logic voltage | <2 VDC (Low) |
| | >10 VDC (High) |
| Input type | PNP (current sinking) |
| Input voltage | 30 VDC max. |
| Output voltage | 10 to 30 VDC (external supply required) |
| Contact | open drain p-channel MOSFET |
| Load capacity | 30 VDC / 100 mA (ohmic load) |
| | |

Strain Gage Measurement

| Bridge configuration(s) | resistive full-bridge (4/6 resistive half-bridge (3/5 resistive quarter-bridge | 5-wire) | e, with bridge completion terr | ninal) |
|------------------------------------|--|-------------|--|---------------|
| Allowable sensor cable length | <300 m (DC and 600 Hz CF excitation) <100 m ¹ (4.8 kHz CF excitation) | | | |
| Shunt resistor | 100 kΩ internal resistor | | | |
| Bridge excitation | 2.5 - 5 VDC 2.5 - 5 Veff (Carrier Frequency) | | | |
| Bridge excitation stability | <0.01% / 24 hrs | | | |
| Bridge excitation drift | <0.02%/10K | | | |
| | 5 VDC | 5 Veff (CF) | 2.5 VDC | 2.5 Veff (CF) |
| Allowable sensor resistance | >300 Ω | >300Ω | >100Ω | >100 Ω |
| Input range | ±1.25 mV/V | ±1.25 mV/V | ±2.5 mV/V | ±2.5 mV/V |
| | ±2.5 mV/V | ±2.5 mV/V | ±5 mV/V | ±5 mV/V |
| | ±25 mV/V | ±25 mV/V | ±50 mV/V | ±50 mV/V |
| | ±50 mV/V | ±50 mV/V | ±100 mV/V | ±100 mV/V |
| | ±100 mV/V | ±100 mV/V | ±200 mV/V | ±200 mV/V |
| | ±200 mV/V | ±200 mV/V | ±400 mV/V | ±400 mV/V |
| | ±500 mV/V | ±500 mV/V | ±1000 mV/V | ±1000 mV/V |
| Long-term stability | <0.2 μV/V / 24 hrs (DC excitation) <0.1 μV/V / 24 hrs (CF excitation) | | <2 μV/V / 8000 hrs (DC <1 μV/V / 8000 hrs (CF | , |
| Temperature drift (range 2.5 mV/V) | <0.2 µV/V / 10 K Offset drift | | < 0.05 % / 10 K Gain drif | t |
| Signal-to-noise ratio | < 0.3 µV/V at 10 Hz | | <1 µV/V at 100 Hz | |

 $^{^{\,1}\,}$ low capacity sensor cable is strongly recommended



Measurement Module for Strain Gage and LVDT/RVDT

LVDT/RVDT Measurement

| Sensor connection | 4- / 6-wire | |
|------------------------------------|-------------------------------|----------------------------|
| Sensor excitation (selectable) | 5 Veff | 2.5 Veff |
| Allowable sensor resistance | >300 Ω | >100 Ω |
| Input range | ±1.25 mV/V | ±2.5 mV/V |
| | ±2.5 mV/V | ±5 mV/V |
| | ±25 mV/V | ±50 mV/V |
| | ±50 mV/V | ±100 mV/V |
| | ±100 mV/V | ±200 mV/V |
| | ±200 mV/V | ±400 mV/V |
| | ±500 mV/V | ±1000 mV/V |
| Allowable sensor cable length | <100 m ¹ | |
| Long-term stability | <0.1 µV/V / 24 hrs | <1 µV/V / 8000 hrs |
| Temperature drift (range 2.5 mV/V) | <0.2 µV/V / 10 K Offset drift | < 0.05 % / 10 K Gain drift |
| Signal-to-noise ratio | < 0.3 µV/V at 10 Hz | <1 µV/V at 100 Hz |

¹ low capacity sensor cable is strongly recommended

Digital to Analog Conversion

| Resolution | 16-bit |
|---------------|--------------------|
| Update rate | 10 kHz per channel |
| Settling time | Зµѕ |

Communication Interface

| Protocols | proprietary Localbus (115200 bps to 24 Mbps, latency <100 ns) ASCII (19200 bps to 115200 bps) Modbus RTU Profibus-DP (19200 bps to 12 Mbps) (special Firmware required) |
|---------------------|---|
| Data format | 8E1 |
| Electrical standard | ANSI/TIA/EIA-485-A, 2-wire |

Power Supply

| Input voltage | 10 to 30 VDC, overvoltage and overcurrent protection |
|-------------------------|--|
| Power consumption | 2.5 W (approx.) |
| Input voltage influence | <0.001 % / V |

Environmental Specifications

| Electromagnetic compatibility (EMC) | according to IEC 61000-4 and EN 55011 |
|-------------------------------------|---------------------------------------|
| Operating temperature | -20°C to +60°C |
| Storage temperature | -40°C to +85°C |
| Relative humidity | 5 - 95 % at 50°C (non-condensing) |



Measurement Module for Strain Gage and LVDT/RVDT

Remarks

| Validity of all listed specifications are subject to a warm-up period of at least 45 minutes |
|--|
| Specifications subject to change without notice |

Mechanical information

| Material | Aluminum |
|--------------------------|-------------------|
| Measurements (W x H x D) | 30 x 125 x 155 mm |
| Weight | approx. 200 g |

Ordering Information

| Article number | 796640 |
|----------------|---|
| Accessories | Terminal B4/120-A106, article number 894387 |
| | Terminal B4/350-A106, article number 894488 |

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